

DATA SHEET

For a complete data sheet, please also download:

- The IC04 LOCMOS HE4000B Logic Family Specifications HEF, HEC
- The IC04 LOCMOS HE4000B Logic Package Outlines/Information HEF, HEC

HEF4518B **MSI** Dual BCD counter

Product specification
File under Integrated Circuits, IC04

January 1995

Dual BCD counter

HEF4518B

MSI

DESCRIPTION

The HEF4518B is a dual 4-bit internally synchronous BCD counter. The counter has an active HIGH clock input (CP₀) and an active LOW clock input ($\overline{\text{CP}}_1$), buffered outputs from all four bit positions (O₀ to O₃) and an active HIGH overriding asynchronous master reset input (MR). The counter advances on either the LOW to HIGH transition of the CP₀ input if $\overline{\text{CP}}_1$ is HIGH or the HIGH to

LOW transition of the $\overline{\text{CP}}_1$ input if CP₀ is LOW. Either CP₀ or $\overline{\text{CP}}_1$ may be used as the clock input to the counter and the other clock input may be used as a clock enable input. A HIGH on MR resets the counter (O₀ to O₃ = LOW) independent of CP₀, $\overline{\text{CP}}_1$. Schmitt-trigger action in the clock input makes the circuit highly tolerant to slower clock rise and fall times.

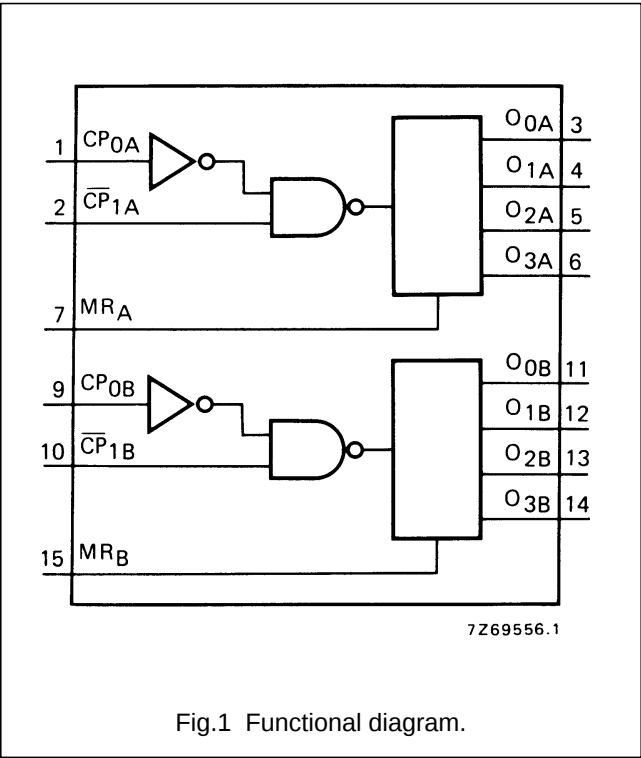


Fig.1 Functional diagram.

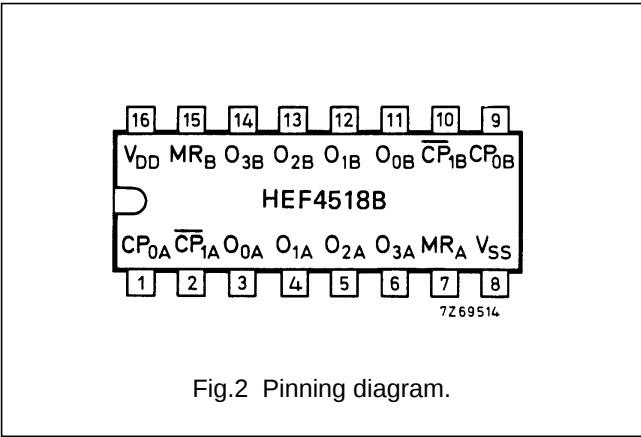


Fig.2 Pinning diagram.

PINNING

- | | |
|---|---------------------------------|
| CP _{0A} , CP _{0B} | clock inputs (L to H triggered) |
| $\overline{\text{CP}}_{1A}$, $\overline{\text{CP}}_{1B}$ | clock inputs (H to L triggered) |
| MR _A , MR _B | master reset inputs |
| O _{0A} to O _{3A} | outputs |
| O _{0B} to O _{3B} | outputs |

APPLICATION INFORMATION

- Some examples of applications for the HEF4518B are:
- Multistage synchronous counting.
 - Multistage asynchronous counting.
 - Frequency dividers.

FAMILY DATA, I_{DD} LIMITS category MSI

See Family Specifications

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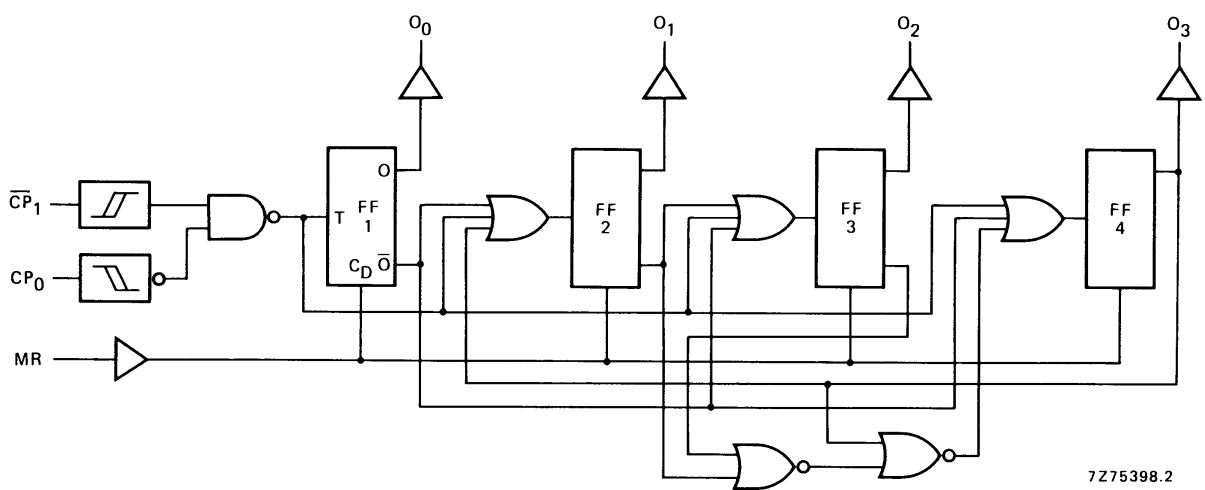


Fig.3 Logic diagram (one counter).

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FUNCTION TABLE

CP ₀	$\overline{\text{CP}}_1$	MR	MODE
	H	L	counter advances
L		L	counter advances
	X	L	no change
X		L	no change
	L	L	no change
H		L	no change
X	X	H	O ₀ to O ₃ = LOW

Notes

- H = HIGH state (the more positive voltage)
L = LOW state (the less positive voltage)
X = state is immaterial
 = positive-going transition
 = negative-going transition

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AC CHARACTERISTICS

 $V_{SS} = 0\text{ V}$; $T_{amb} = 25\text{ }^{\circ}\text{C}$; $C_L = 50\text{ pF}$; input transition times $\leq 20\text{ ns}$

	V_{DD} V	SYMBOL	MIN.	TYP.	MAX.	TYPICAL EXTRAPOLATION FORMULA
Propagation delays $CP_0, \overline{CP}_1 \rightarrow O_n$ HIGH to LOW LOW to HIGH $MR \rightarrow O_n$ HIGH to LOW	5	t_{PHL}	120	240	ns	93 ns + (0,55 ns/pF) C_L
	10		55	110	ns	44 ns + (0,23 ns/pF) C_L
	15		40	80	ns	32 ns + (0,16 ns/pF) C_L
	5	t_{PLH}	120	240	ns	93 ns + (0,55 ns/pF) C_L
	10		55	110	ns	44 ns + (0,23 ns/pF) C_L
	15		40	80	ns	32 ns + (0,16 ns/pF) C_L
	5	t_{PHL}	75	150	ns	48 ns + (0,55 ns/pF) C_L
	10		35	70	ns	24 ns + (0,23 ns/pF) C_L
	15		25	50	ns	17 ns + (0,16 ns/pF) C_L
Output transition times HIGH to LOW LOW to HIGH	5	t_{THL}	60	120	ns	10 ns + (1,0 ns/pF) C_L
	10		30	60	ns	9 ns + (0,42 ns/pF) C_L
	15		20	40	ns	6 ns + (0,28 ns/pF) C_L
	5	t_{TLH}	60	120	ns	10 ns + (1,0 ns/pF) C_L
	10		30	60	ns	9 ns + (0,42 ns/pF) C_L
	15		20	40	ns	6 ns + (0,28 ns/pF) C_L
Minimum CP_0 pulse width; LOW	5	t_{WCPL}	60	30	ns	see also waveforms Figs 4 and 5
	10		30	15	ns	
	15		20	10	ns	
Minimum $\overline{CP}_1$ pulse width; HIGH	5	t_{WCPH}	60	30	ns	
	10		30	15	ns	
	15		20	10	ns	
Minimum MR pulse width; HIGH	5	t_{WMRH}	30	15	ns	
	10		20	10	ns	
	15		16	8	ns	
Recovery time for MR	5	t_{RMR}	50	25	ns	
	10		30	15	ns	
	15		20	10	ns	
Set-up times $CP_0 \rightarrow \overline{CP}_1$ $\overline{CP}_1 \rightarrow CP_0$	5	t_{su}	50	25	ns	
	10		30	15	ns	
	15		20	10	ns	
	5	t_{su}	50	25	ns	
	10		30	15	ns	
	15		20	10	ns	
Maximum clock pulse frequency	5	f_{max}	8	16	MHz	
	10		15	30	MHz	
	15		20	40	MHz	

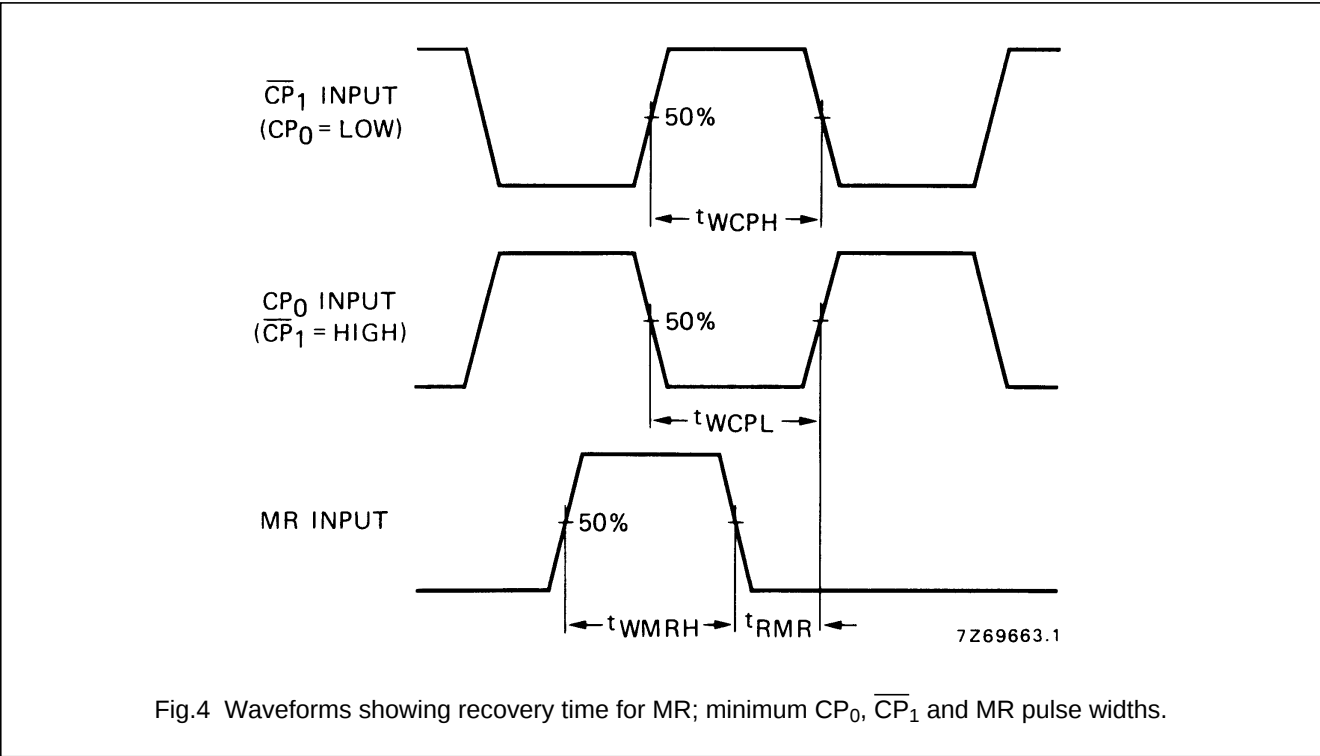
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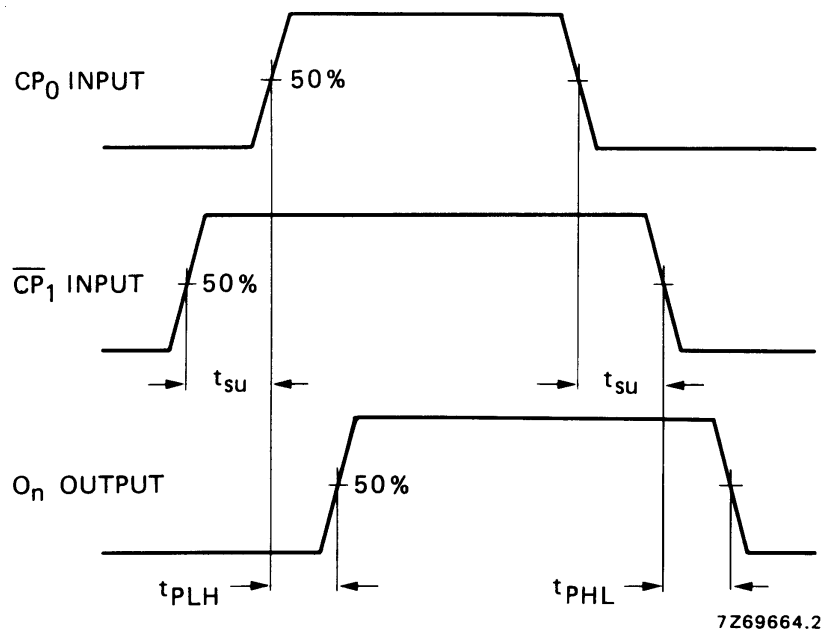
AC CHARACTERISTICS

V_{SS} = 0 V; T_{amb} = 25 °C; input transition times ≤ 20 ns

	V _{DD} V	TYPICAL FORMULA FOR P (μW)	
Dynamic power dissipation per package (P)	5	$750f_i + \sum (f_o C_L) \times V_{DD}^2$	where f _i = input freq. (MHz) f _o = output freq. (MHz) C _L = load capacitance (pF) Σ (f _o C _L) = sum of outputs V _{DD} = supply voltage (V)
	10	$3300 f_i + \sum (f_o C_L) \times V_{DD}^2$	
	15	$8000 f_i + \sum (f_o C_L) \times V_{DD}^2$	



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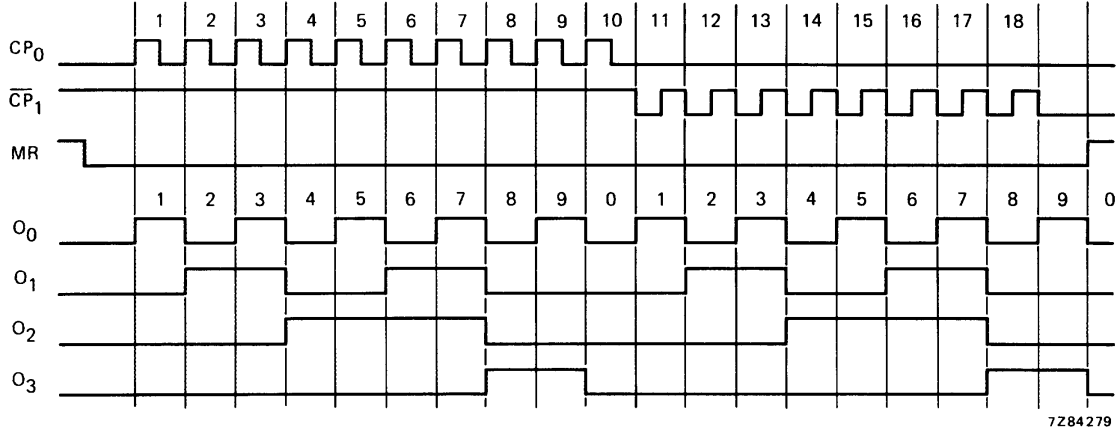


Fig.6 Timing diagram.